

# SGM853 Low Power Reset Timer with Two Voltage Detector Functions

# **GENERAL DESCRIPTION**

The SGM853 is a reset timer with dual voltage detector featuring low power and small solution size for applications requiring a highly integrated solution.

As a reset timer, the SGM853 has an input (RESET pin) and a fixed delay push-pull 1× output (RESET\_OUT pin). It generates a low-level reset signal for 500ms (TYP) if the input has a low-level voltage for 8s (TYP). Then the reset signal returns to high for subsequent loads reset.

The SGM853 also has two voltage detector functions with 4 inputs and 2 outputs including a push-pull 1× output and a push-pull 2× output. The 2× output provides greater source and sink current. On the one side, the ALL PG output pin indicates whether the 3 input pins (SUS PG, VCC PG and AUX PG) are in a high-level voltage at the same time. If the above 3 input pins are high at the same time, the ALL PG output pin is set to high, and vice versa. On the other side, the PROCHOT\_OUT output pin generates a fixed 12ms delay time and indicates whether the PROCHOT input pin is in a high-level voltage. If PROCHOT rises to high-level voltage, PROCHOT\_OUT rises after a fixed 12ms delay time, and PROCHOT OUT falls immediately when PROCHOT falls.

The SGM853 operates over a junction temperature range of -40°C to +125°C. It is available in a Green UTQFN-1.6×1.6-12AL package.

## **FEATURES**

- Low Power Consumption
- Output Options:
  - + 2 Outputs: Push-Pull 1×
  - 1 Output: Push-Pull 2×
- Available in a Green UTQFN-1.6×1.6-12AL Package

### **APPLICATIONS**

**Smart Phones** 

Tablet PCs

Servers

Workstations

Storage Systems

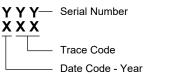
Networking/Telecommunication Equipment

## PACKAGE/ORDERING INFORMATION

MODEL PACKAGE DESCRIPTION		SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION	
SGM853	UTQFN-1.6×1.6-12AL	-40°C to +125°C	SGM853XUSH12G/TR	00A XXX	Tape and Reel, 3000	

#### MARKING INFORMATION

NOTE: XXX = Date Code and Trace Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage on VDD Relative to GND.	
DC Input VoltageGND -	
Current at Input Pin	IIIIA 10 IIIIA
Maximum Average or DC Current	
Push-Pull 1×	20mA
Push-Pull 2×	40mA
Input leakage (Absolute Value)	1000nA
Maximum Average or DC Current	90mA
Package Thermal Resistance	
UTQFN-1.6×1.6-12AL, θ <sub>JA</sub>	133°C/W
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	4000V
CDM	1000V

## RECOMMENDED OPERATING CONDITIONS

Operating Junction Temperature Range......-40°C to +125°C

#### **OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

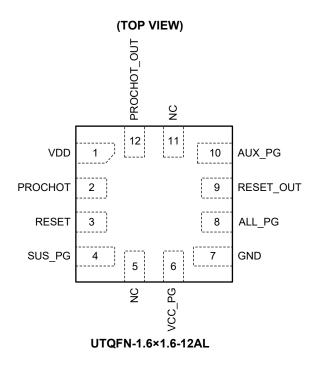
#### **ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

#### **DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

# **PIN CONFIGURATION**



# **PIN DESCRIPTION**

PIN	NAME	TYPE	FUNCTION
1	VDD	Р	Supply Voltage.
2	PROCHOT	I	Active High Digital Input with Schmitt Trigger.
3	RESET	I	Digital Input with Schmitt Trigger. The reset delay time of 8s.
4	SUS_PG	I	Digital Input with Schmitt Trigger. It has an internal 1.25MΩ pull-down resistor.
5, 11	NC	_	Leave it floating or connect it to GND.
6	VCC_PG	1	Digital Input with Schmitt Trigger. It has an internal 1.25MΩ pull-down resistor.
7	GND	G	Ground.
8	ALL_PG	0	Push-Pull 1× Output.
9	RESET_OUT	0	Push-Pull 1× Output.
10	AUX_PG	ı	Digital Input with Schmitt Trigger. It has an internal 1.25MΩ pull-down resistor.
12	PROCHOT_OUT	0	Active High Push-Pull 2× Output.

NOTE: I: Input, O: Output, G: Ground, P: Power.

# **ELECTRICAL CHARACTERISTICS**

 $(T_J = -40^{\circ}C \text{ to } +125^{\circ}C, \text{ typical values are at } T_J = +25^{\circ}C, \text{ unless otherwise noted.})$ 

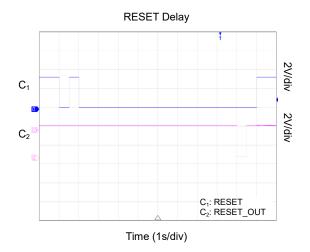
PARAMETER	SYMBOL	CON	IDITIONS	MIN	TYP	MAX	UNITS	
Supply Voltage	V <sub>DD</sub>			1.7	3.3	5.5	V	
Capacitor Value at VDD	$C_{VDD}$				0.1		μF	
Input Capacitance	C <sub>IN</sub>				4		pF	
Quiescent Current	ΙQ	Static inputs and floating		0.3	0.9	μΑ		
Active Current	I <sub>A</sub>	Static outputs, keep RI	ESET pin low for 8.5s		0.8	1.6	μΑ	
Maximal Voltage Applied to Any Pin in High-Impedance State	V <sub>OUT</sub>					$V_{DD}$	V	
Maximum Average or DC Current		T <sub>J</sub> = +85°C				66	mA	
through VDD Pin (Per chip side)	I <sub>VDD</sub>	T <sub>J</sub> = +85°C T <sub>J</sub> = +85°C T <sub>J</sub> = +110°C V <sub>DD</sub> = 3.3V V <sub>DD</sub> = 5.0V V <sub>DD</sub> = 3.3V V <sub>DD</sub> = 5.0V P <sub>DD</sub> = 1.8V P <sub>DD</sub> = 1.8V P <sub>DD</sub> = 5.0V P <sub>DD</sub> = 0.2V P <sub>DD</sub> = 1.8V P <sub>DD</sub> = 5.0V P <sub>DD</sub> = 0.4V P <sub>DD</sub> = 5.0V P <sub>DD</sub> = 0.4V P <sub>DD</sub> = 5.0V P <sub>DD</sub> = 0.4V P <sub>DD</sub> = 5.0V P <sub>DD</sub> = 0.5V P <sub>D</sub>			65	mA		
Maximum Average or DC Current		T <sub>J</sub> = +85°C				34	mA	
through GND Pin (Per chip side)	$I_{GND}$	T <sub>J</sub> = +110°C				31	mA	
		V <sub>DD</sub> = 1.8V		1.04		$V_{DD}$		
High-Level Input Voltage	$V_{IH}$	V <sub>DD</sub> = 3.3V		1.85		$V_{DD}$	V	
		V <sub>DD</sub> = 5.0V		2.94		$V_{DD}$	-	
		V <sub>DD</sub> = 1.8V		0		0.62		
Low-Level Input Voltage	$V_{IL}$	V <sub>DD</sub> = 3.3V				1.42	V	
		V <sub>DD</sub> = 5.0V		0		1.95		
		Push-pull 1×, open-drain PMOS 1×	I <sub>OH</sub> = 100μA, V <sub>DD</sub> = 1.8V	1.60	1.79		- V	
	V <sub>он</sub>		I <sub>OH</sub> = 3mA, V <sub>DD</sub> = 3.3V	2.71	3.12			
			I <sub>OH</sub> = 5mA, V <sub>DD</sub> = 5.0V	4.21	4.77			
High-Level Output Voltage		Push-pull 2×,	$I_{OH} = 100 \mu A, V_{DD} = 1.8 V$	1.61	1.79			
			I <sub>OH</sub> = 3mA, V <sub>DD</sub> = 3.3V	2.84	3.21			
		open didin'i Mee 2.	I <sub>OH</sub> = 5mA, V <sub>DD</sub> = 5.0V	4.34	4.89			
			$I_{OL} = 100 \mu A, V_{DD} = 1.8 V$		0.006	0.01		
		Push-pull 1×	$I_{OL} = 3mA, V_{DD} = 3.3V$		0.13	0.18	1	
Lave Lavel Outrot Valtage	V		$I_{OL} = 5mA, V_{DD} = 5.0V$		0.20	0.26		
Low-Level Output Voltage	$V_{OL}$		$I_{OL} = 100 \mu A, V_{DD} = 1.8 V$		0.003	0.01	V	
		Push-pull 2×	$I_{OL} = 3mA, V_{DD} = 3.3V$		0.07	0.1		
					0.1	0.14		
		Decil well 4 o		0.9	1.58			
		open-drain PMOS 1×	$V_{OH} = 2.4V, V_{DD} = 3.3V$	7.3	11.96		mA	
High Lavel Output Current			V <sub>OH</sub> = 2.4V, V <sub>DD</sub> = 5.0V	19.2	26.83			
High-Level Output Current	I <sub>OH</sub>	D 1 110		1.67	3.07			
		open-drain PMOS 2×	V <sub>OH</sub> = 2.4V, V <sub>DD</sub> = 3.3V	13.95	23.43			
			V <sub>OH</sub> = 2.4V, V <sub>DD</sub> = 5.0V	36.50	52.24		1	
			V <sub>OL</sub> = 0.15V, V <sub>DD</sub> = 1.8V	1.49	2.3			
		Push-pull 1×	$V_{OL} = 0.4V, V_{DD} = 3.3V$	5.93	8.64			
Lave Lavel Outrot Comment			$V_{OL} = 0.4V, V_{DD} = 5.0V$	7	9.79			
Low-Level Output Current	I <sub>OL</sub>		V <sub>OL</sub> = 0.15V, V <sub>DD</sub> = 1.8V	2.9	4.49		mA	
		Push-pull 2×	$V_{OL} = 0.4V, V_{DD} = 3.3V$	10.7	16.84		<del>-</del>	
			$V_{OL} = 0.4V, V_{DD} = 5.0V$	12.76	19.09			

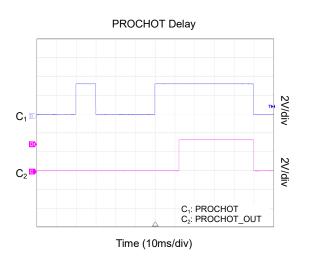
# **ELECTRICAL CHARACTERISTICS (Continued)**

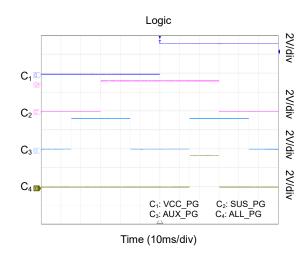
 $(T_J = -40^{\circ}C \text{ to } +125^{\circ}C, \text{ typical values are at } T_J = +25^{\circ}C, \text{ unless otherwise noted.})$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Internal Pull-Down Resistance	R <sub>PULL_DOWN</sub>	SUS_PG, VCC_PG and AUX_PG Pins	967	1248	1524	kΩ
Delevit Time		T <sub>J</sub> = +25°C		8	8.36	
Delay1 Time	t <sub>DLY1</sub>	T <sub>J</sub> = -40°C to +125°C	7.49	8	8.89	S
Delay2 Time		T <sub>J</sub> = +25°C	475.94	500	526.02	ms
Delay2 Time	t <sub>DLY2</sub>	$T_J = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$	460.09	500	561.94	
Dolov2 Time		T <sub>J</sub> = +25°C	11.59	12	12.8	ma.a
Delay3 Time	IDLY3	$t_{DLY3}$ $T_J = -40^{\circ}C$ to +125°C 11.2		12	13.66	ms
Startup Time	t <sub>SU</sub>	From V <sub>DD</sub> rising past 1.35V		0.05		ms
Power-On Threshold	V <sub>PON</sub>	V <sub>DD</sub> level required to start up the chip	1.223	1.283	1.343	V
Power-Off Threshold V		V <sub>DD</sub> level required to switch off the chip	0.73	0.91	1.089	V

# TYPICAL PERFORMANCE CHARACTERISTICS









# **FUNCTIONAL BLOCK DIAGRAM**

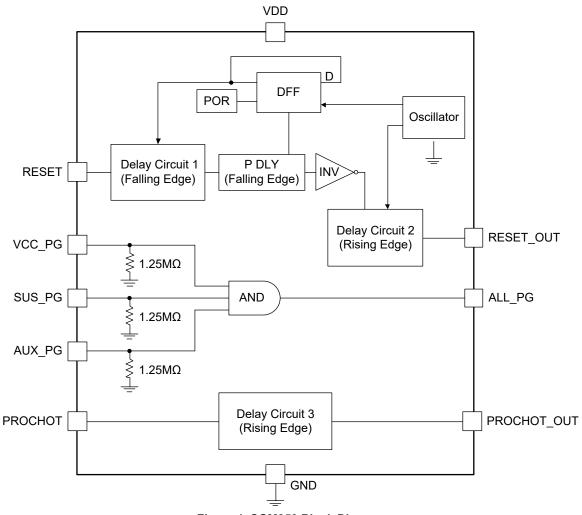


Figure 1. SGM853 Block Diagram

# APPLICATION INFORMATION

The SGM853 is both a reset timer and a dual voltage detector that features low power and small solution size for applications requiring a highly integrated solution.

#### **Reset Timer**

A reset event occurs and forces the reset input (RESET pin) in a low-level input voltage for at least 8s. The RESET\_OUT generates a low-level reset signal for 500ms to shut down the subsequent loads or PMIC. Then the reset signal returns to a high-level voltage until the input pin is in the next low-level state for more than 8s.

If the RESET is released and returns to high-level voltage within 8s, the counter resets and the RESET OUT remains high.

#### **Detector 1: ALL PG**

The ALL PG output pin monitors 3 input pins at the same time: SUS PG, VCC PG and AUX PG pins. If the application scenario requires voltage detection on up to 3 power rails, connect the power rail to the above three input pins respectively.

## **Detector 2: PROCHOT and PROCHOT\_OUT**

The PROCHOT OUT pin is used to monitor PROCHOT input pin. If the PROCHOT input rises to a high-level voltage, the PROCHOT\_OUT rises after a fixed delay time of 12ms, and PROCHOT\_OUT falls immediately when PROCHOT in low-level voltage. If PROCHOT keeps in high-level voltage within 12ms, the PROCHOT\_OUT remains low.

#### REVISION HISTORY

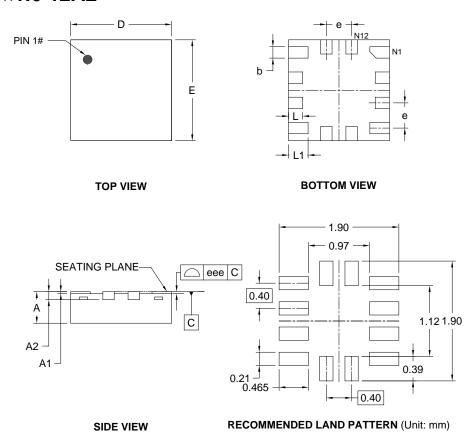
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (OCTOBER 2022) to REV.A

Page



# PACKAGE OUTLINE DIMENSIONS UTQFN-1.6×1.6-12AL

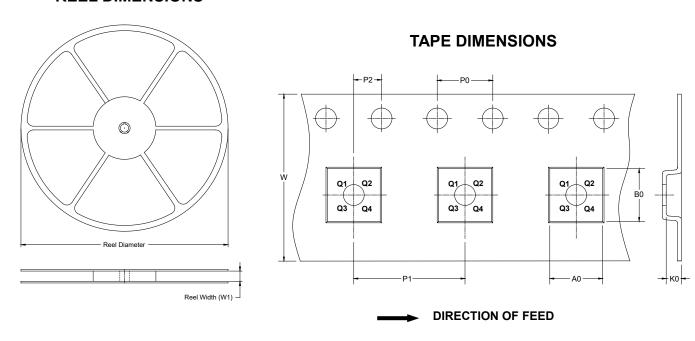


Cumbal	Dimensions In Millimeters						
Symbol	MIN	MOD	MAX				
А	0.450	0.500	0.550				
A1	0.000	-	0.050				
A2							
b	0.130	0.180	0.230				
D	1.500	1.600	1.700				
Е	1.500	1.600	1.700				
L	0.125	0.225	0.325				
L1	0.210 0.310		0.410				
е	0.400 BSC						
eee	0.080						

NOTE: This drawing is subject to change without notice.

# TAPE AND REEL INFORMATION

## **REEL DIMENSIONS**

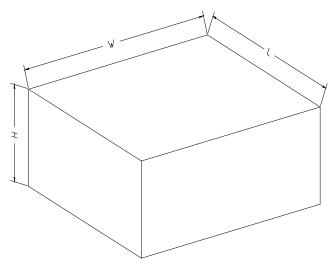


NOTE: The picture is only for reference. Please make the object as the standard.

# **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
UTQFN-1.6×1.6-12AL	7"	9.0	1.80	1.80	0.69	4.0	4.0	2.0	8.0	Q2

# **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

# **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5